

# TC74AC32P, TC74AC32F, TC74AC32FT

## Quad 2-Input OR Gate

The TC74AC32 is an advanced high speed CMOS 2-INPUT OR GATE fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

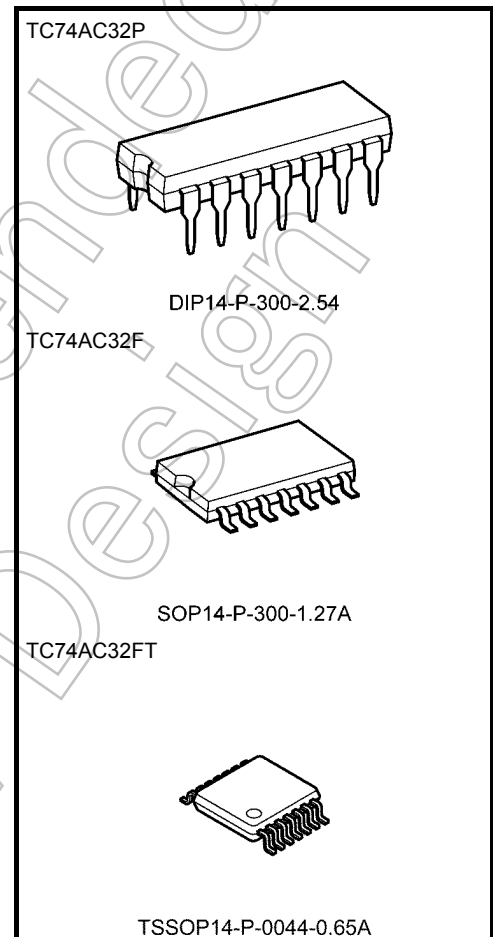
It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 2 stages including buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### Features

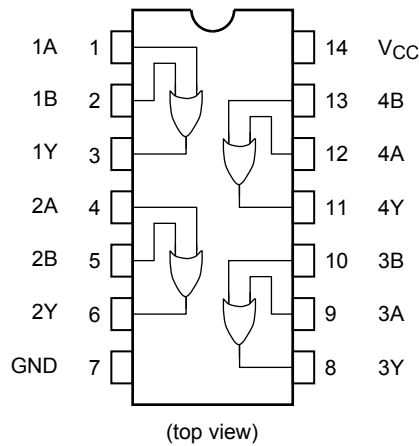
- High speed:  $t_{pd} = 4.1 \text{ ns (typ.) at } V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu\text{A (max) at } T_a = 25^\circ\text{C}$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC} \text{ (min)}$
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24 \text{ mA (min)}$   
 Capability of driving 50  $\Omega$  transmission lines.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range:  $V_{CC (opr)} = 2 \text{ to } 5.5 \text{ V}$
- Pin and function compatible with 74F32



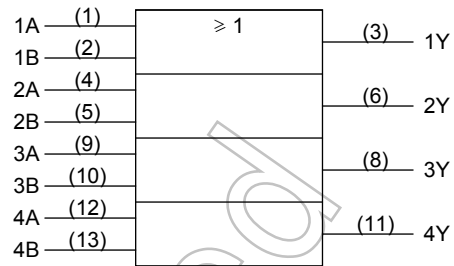
|                      |                 |
|----------------------|-----------------|
| Weight               |                 |
| DIP14-P-300-2.54     | : 0.96 g (typ.) |
| SOP14-P-300-1.27A    | : 0.18 g (typ.) |
| TSSOP14-P-0044-0.65A | : 0.06 g (typ.) |

Not Recommended for New

## Pin Assignment



## IEC Logic Symbol



## Truth Table

| A | B | Y |
|---|---|---|
| H | H | H |
| L | H | H |
| H | L | H |
| L | L | L |

## Absolute Maximum Ratings (Note 1)

| Characteristics             | Symbol    | Rating                             | Unit |
|-----------------------------|-----------|------------------------------------|------|
| Supply voltage range        | $V_{CC}$  | -0.5 to 7.0                        | V    |
| DC input voltage            | $V_{IN}$  | -0.5 to $V_{CC} + 0.5$             | V    |
| DC output voltage           | $V_{OUT}$ | -0.5 to $V_{CC} + 0.5$             | V    |
| Input diode current         | $I_{IK}$  | ±20                                | mA   |
| Output diode current        | $I_{OK}$  | ±50                                | mA   |
| DC output current           | $I_{OUT}$ | ±50                                | mA   |
| DC $V_{CC}$ /ground current | $I_{CC}$  | ±100                               | mA   |
| Power dissipation           | $P_D$     | 500 (DIP) (Note 2)/180 (SOP/TSSOP) | mW   |
| Storage temperature         | $T_{stg}$ | -65 to 150                         | °C   |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of  $T_a = -40$  to  $65^\circ\text{C}$ . From  $T_a = 65$  to  $85^\circ\text{C}$ , a derating factor of  $-10$  mW/°C should be applied up to 300 mW.

## Operating Ranges (Note)

| Characteristics          | Symbol    | Rating                               | Unit |
|--------------------------|-----------|--------------------------------------|------|
| Supply voltage           | $V_{CC}$  | 2.0 to 5.5                           | V    |
| Input voltage            | $V_{IN}$  | 0 to $V_{CC}$                        | V    |
| Output voltage           | $V_{OUT}$ | 0 to $V_{CC}$                        | V    |
| Operating temperature    | $T_{opr}$ | -40 to 85                            | °C   |
| Input rise and fall time | dt/dV     | 0 to 100 ( $V_{CC} = 3.3 \pm 0.3$ V) | ns/V |
|                          |           | 0 to 20 ( $V_{CC} = 5 \pm 0.5$ V)    |      |

Note: The operating ranges must be maintained to ensure the normal operation of the device.  
Unused inputs must be tied to either  $V_{CC}$  or GND.

## Electrical Characteristics

### DC Characteristics

| Characteristics           | Symbol   | Test Condition                | $T_a = 25^\circ\text{C}$   |      |      | $T_a = -40$ to $85^\circ\text{C}$ |      | Unit      |               |                          |
|---------------------------|----------|-------------------------------|----------------------------|------|------|-----------------------------------|------|-----------|---------------|--------------------------|
|                           |          |                               | $V_{CC}$ (V)               | Min  | Typ. | Max                               | Min  |           | Max           |                          |
| High-level input voltage  | $V_{IH}$ | —                             | 2.0                        | 1.50 | —    | —                                 | 1.50 | —         | V             |                          |
|                           |          |                               | 3.0                        | 2.10 | —    | —                                 | 2.10 | —         |               |                          |
|                           |          |                               | 5.5                        | 3.85 | —    | —                                 | 3.85 | —         |               |                          |
| Low-level input voltage   | $V_{IL}$ | —                             | 2.0                        | —    | —    | 0.50                              | —    | 0.50      | V             |                          |
|                           |          |                               | 3.0                        | —    | —    | 0.90                              | —    | 0.90      |               |                          |
|                           |          |                               | 5.5                        | —    | —    | 1.65                              | —    | 1.65      |               |                          |
| High-level output voltage | $V_{OH}$ | $V_{IN} = V_{IH}$ or $V_{IL}$ | $I_{OH} = -50 \mu\text{A}$ | 2.0  | 1.9  | 2.0                               | —    | 1.9       | —             | V                        |
|                           |          |                               |                            | 3.0  | 2.9  | 3.0                               | —    | 2.9       | —             |                          |
|                           |          |                               |                            | 4.5  | 4.4  | 4.5                               | —    | 4.4       | —             |                          |
|                           |          |                               |                            | 3.0  | 2.58 | —                                 | —    | 2.48      | —             |                          |
|                           |          |                               |                            | 4.5  | 3.94 | —                                 | —    | 3.80      | —             |                          |
| Low-level output voltage  | $V_{OL}$ | $V_{IN} = V_{IL}$             | $I_{OL} = 50 \mu\text{A}$  | 2.0  | —    | 0.0                               | 0.1  | —         | 0.1           | V                        |
|                           |          |                               |                            | 3.0  | —    | 0.0                               | 0.1  | —         | 0.1           |                          |
|                           |          |                               |                            | 4.5  | —    | 0.0                               | 0.1  | —         | 0.1           |                          |
|                           |          |                               |                            | 3.0  | —    | —                                 | 0.36 | —         | 0.44          |                          |
|                           |          |                               |                            | 4.5  | —    | —                                 | 0.36 | —         | 0.44          |                          |
| Input leakage current     | $I_{IN}$ | $V_{IN} = V_{CC}$ or GND      | 5.5                        | —    | —    | $\pm 0.1$                         | —    | $\pm 1.0$ | $\mu\text{A}$ |                          |
|                           |          |                               |                            |      |      |                                   |      |           |               | Quiescent supply current |

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

**AC Characteristics (C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 Ω, input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)**

| Characteristics               | Symbol           | Test Condition | Ta = 25°C           |     |      | Ta = -40 to 85°C |     | Unit |     |
|-------------------------------|------------------|----------------|---------------------|-----|------|------------------|-----|------|-----|
|                               |                  |                | V <sub>CC</sub> (V) | Min | Typ. | Max              | Min |      | Max |
| Propagation delay time        | t <sub>pLH</sub> | —              | 3.3 ± 0.3           | —   | 6.1  | 10.3             | 1.0 | 11.9 | ns  |
|                               | t <sub>pHL</sub> |                | 5.0 ± 0.5           | —   | 5.2  | 7.4              | 1.0 | 8.5  |     |
| Input capacitance             | C <sub>IN</sub>  | —              | —                   | 5   | 10   | —                | 10  | pF   |     |
| Power dissipation capacitance | C <sub>PD</sub>  | (Note)         | —                   | 64  | —    | —                | —   | pF   |     |

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

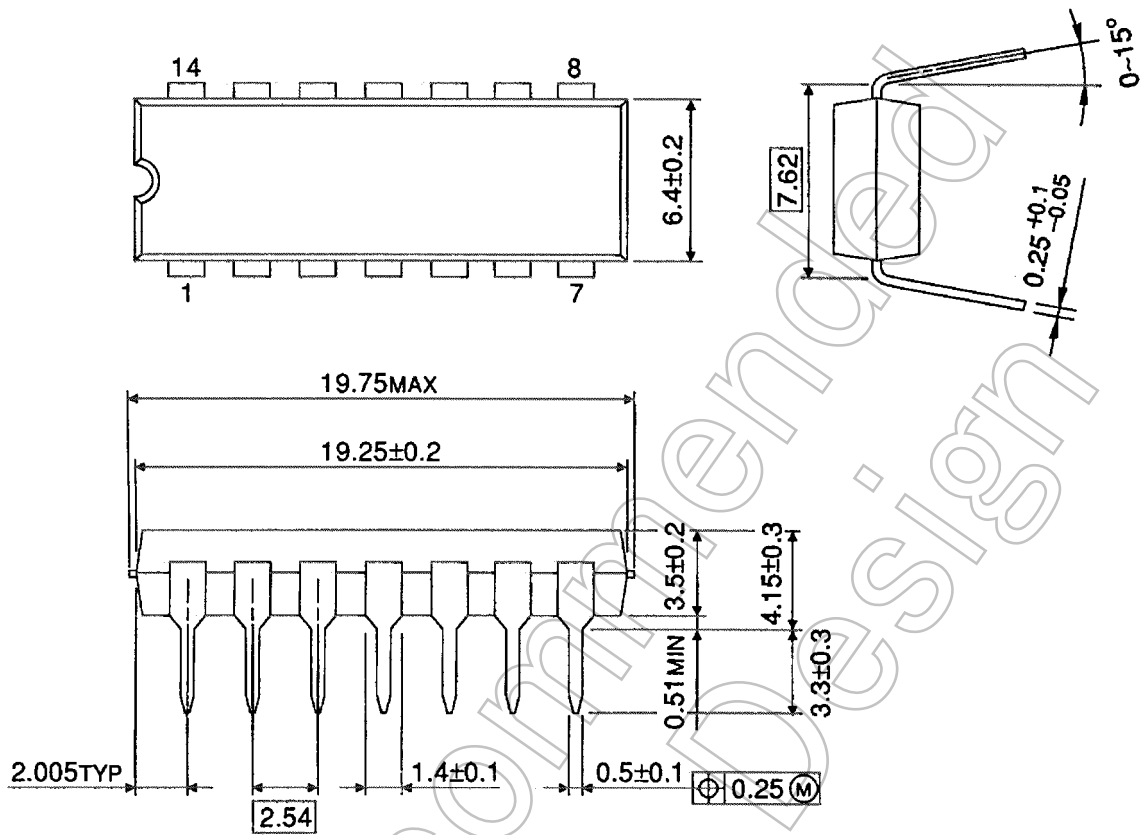
$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

Not Recommended for New Design

## Package Dimensions

DIP14-P-300-2.54

Unit : mm



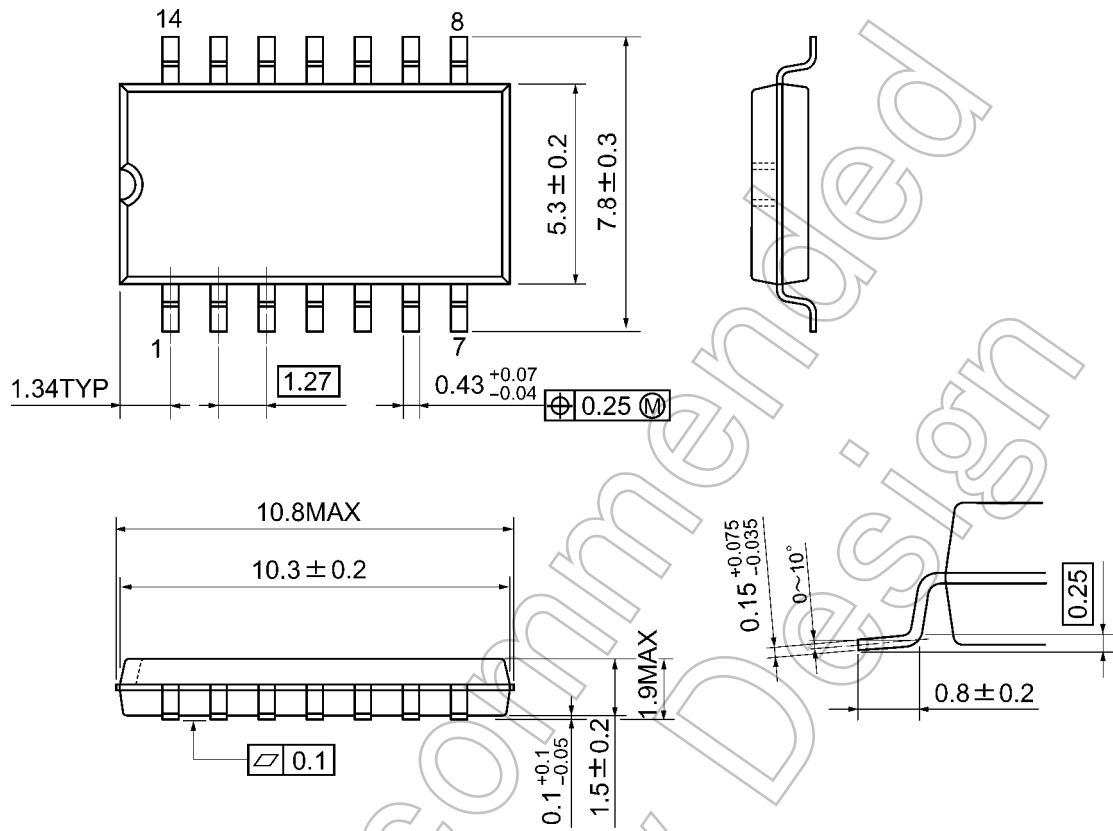
Weight: 0.96 g (typ.)

Not Recommended for New Design

**Package Dimensions**

SOP14-P-300-1.27A

Unit: mm



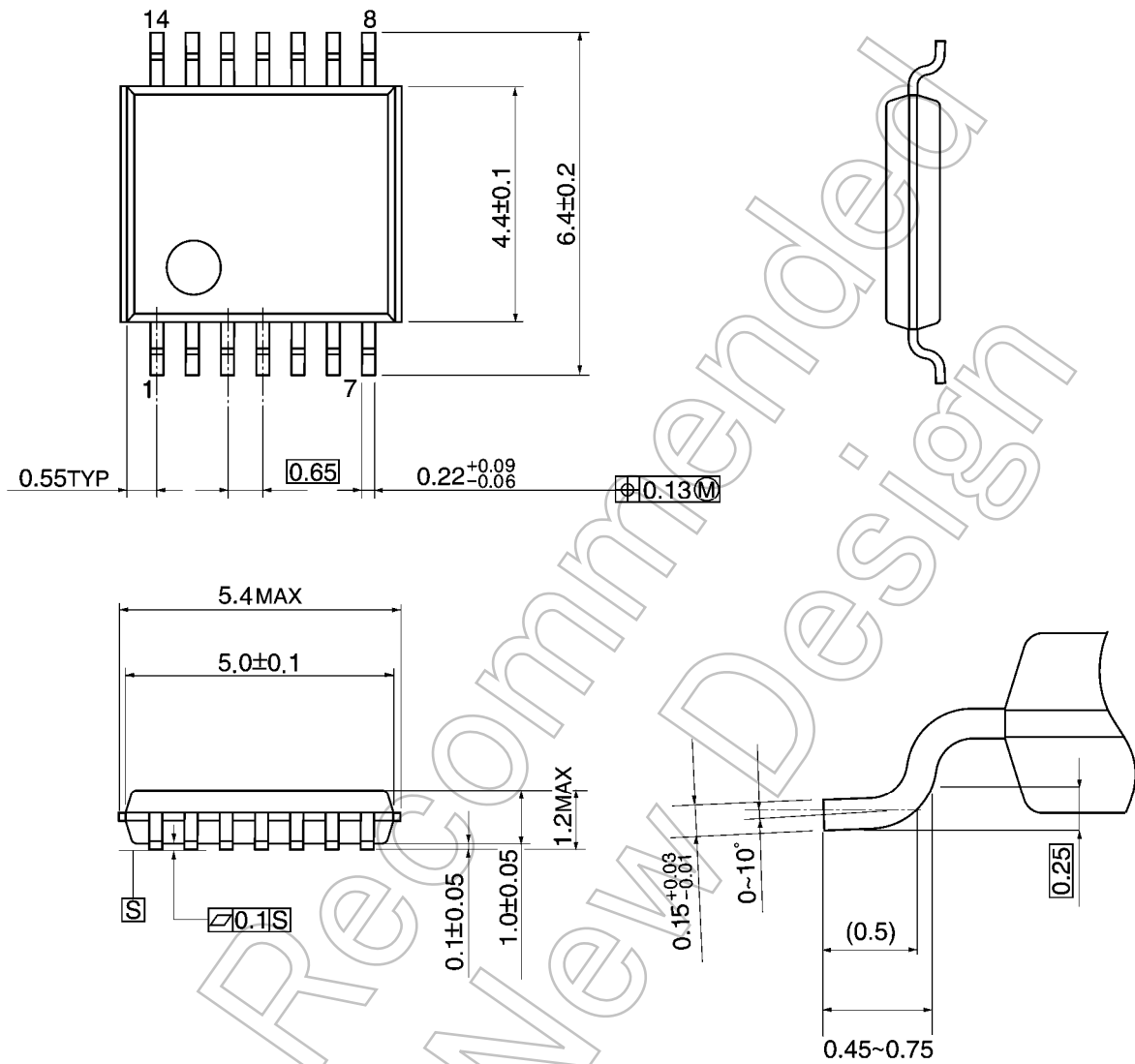
Weight: 0.18 g (typ.)

Not Recommended for New Design

**Package Dimensions**

TSSOP14-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

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